International IOR Rectifier

MBRD320 MBRD330 MBRD340

SCHOTTKY RECTIFIER

3.0 Amp

 $I_{F(AV)} = 3.0Amp$ $V_R = 20/40V$

Major Ratings and Characteristics

Characteristics	Values	Units
I _{F(AV)} Rectangular waveform	3.0	А
V _{RRM}	20/40	V
I _{FSM} @tp=5 µs sine	490	А
V _F @3 Apk, T _J = 125°C	0.49	V
T _J	-40 to 150	°C

Description/ Features

The MBRD320, MBRD330, MBRD340 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and re-

verse battery protection.

- Popular D-PAK outline
- Small foot print, surface mountable
- · Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term



Document Number: 93462

MBRD320, MBRD330, MBRD340

Bulletin PD-20756 rev. F 05/06

Voltage Ratings

Part number	MBRD320	MBRD330	MBRD340
V _R Max. DC Reverse Voltage (V)	20	30	40
V _{RWM} Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

	Parameters	Value	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current	3.0	Α	50% duty cycle @ T _L = 133°C, rectangular wave	
I _{FSM}	Max. Peak One Cycle Non-Repetitive	490		5μs Sine or 3μs Rect. pulse	Following any rated load condition and
	Surge Current	75			with rated V _{RRM} applied
E _{AS}	Non Repetitive Avalanche Energy	8.0	mJ	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1 \text{Amp}, L = 16 \text{mH}$	
I _{AR}	Repetitive Avalanche Current	1.0	Α	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max. Va = 1.5 x Vr typical	

Electrical Specifications

	Parameters	Тур.	Max.	Units	Conditions	3	
V _{FM}	Max. Forward Voltage Drop (1)	0.48	0.6	V	@ 3A	T 05 °C	
	See Fig. 1	0.58	0.7	V	@ 6A	$T_J = 25 ^{\circ}\text{C}$	
		0.41	0.49	V	@ 3A	T 407.00	
		0.55	0.625	V	@ 6A	T _J = 125 °C	
I _{RM}	Max. Reverse Leakage Current (1)	0.02	0.2	mA	T _J = 25 °C		
	See Fig. 2	10.7	20	mA	T _J = 125 °C	$V_R = rated V_R$	
C _T	Typical Junction Capacitance	189	-	pF	V _R = 5V _{DC} (test signal range 100kHz to		
					1Mhz), @ 25°C		
L _S	Typical Series Inductance	5.0	-	nΗ	Measured lead to lead 5mm from package body		
dv/dt	Max. Voltage Rate of Change	-	10000	V/ µs	(Rated V _R)		

(1) Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

	Parameters	Value	Units	Conditions
T _J	Max. Junction Temperature Range (*)	-40 to 150	°C	
T _{stg}	Max. Storage Temperature Range	-40 to 175	°C	
R _{thJC}	Max. Thermal Resistance Junction to Case	6.0	°C/W	DC operation *See Fig. 4
R _{thJA}	Max. Thermal Resistance Junction	80	°C/W	
	to Ambient			
wt	Approximate Weight	0.3 (0.01)	g (oz.)	
	Case Style	D-PAK		Similar to TO-252AA
	Device Marking	MBRD340		

 $[\]frac{\text{dPtot}}{\text{dTj}} < \frac{1}{\text{Rth(j-a)}} \text{ thermal runaway condition for a diode on its own heatsink}$

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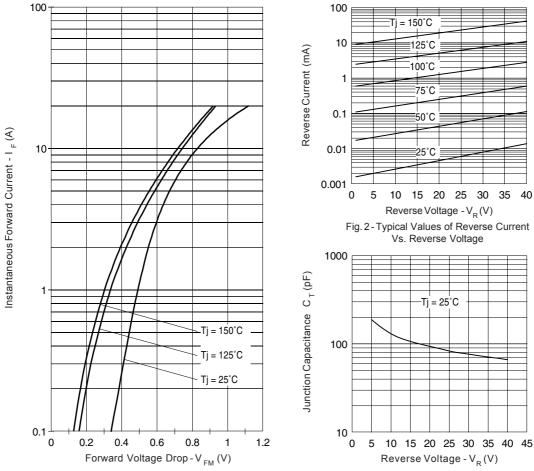


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

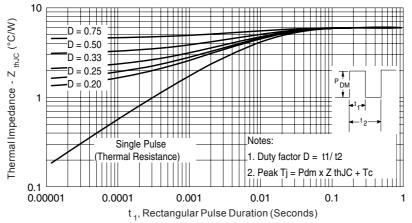


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

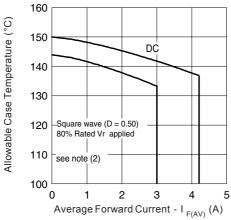


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

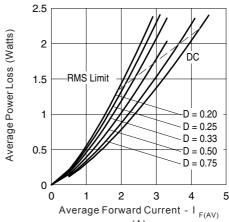


Fig. 6 - Forward Power Loss Characteristics

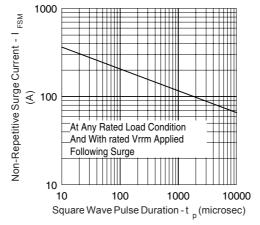
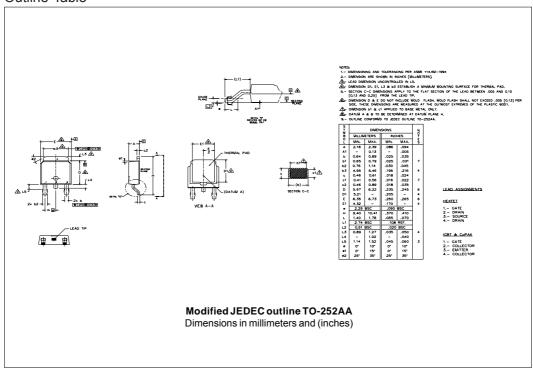


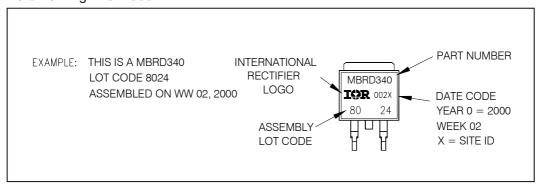
Fig. 7 - Maximum Non-Repetitive Surge Current

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV})xR_{thJC}$; $\label{eq:pd} \operatorname{\mathsf{Pd}} = \operatorname{\mathsf{Forward}} \operatorname{\mathsf{Power}} \operatorname{\mathsf{Loss}} = \operatorname{\mathsf{I}}_{\operatorname{\mathsf{F}(AV)}} x \operatorname{\mathsf{V}}_{\operatorname{\mathsf{FM}}} @ \left(\operatorname{\mathsf{I}}_{\operatorname{\mathsf{F}(AV)}} / \operatorname{\mathsf{D}}\right) \ (\operatorname{\mathsf{see}} \operatorname{\mathsf{Fig.}} 6);$ $Pd_{REV} = Inverse Power Loss = V_{R1} \times I_{R} (1 - D); I_{R} @ V_{R1} = 80\% \text{ rated } V_{R}$

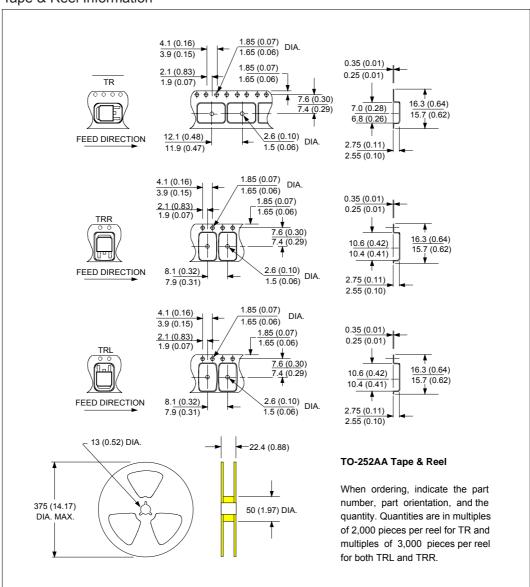
Outline Table



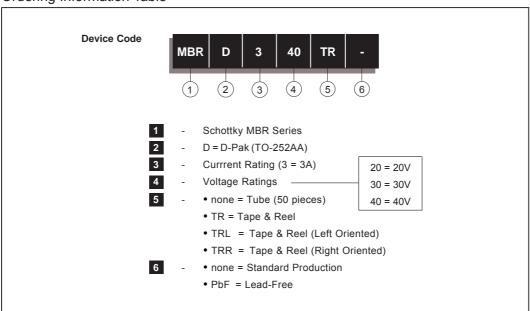
Part Marking Information



Tape & Reel Information



Ordering Information Table



Data and specifications subject to change without notice. This product has been designed and qualified for AEC Q101 Level.

Qualification Standards can be found on IR's Web site.



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05/06



Vishay

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Document Number: 99901 www.vishay.com Revision: 08-Mar-07